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PNP BDX45 – BDX46 – BDX47 NPN BDX42 – BDX43 – BDX44

SILICON PLANAR DARLINGTON TRANSISTORS

The BDX45, BDX46 and BDX47 are silicon PNP planar Darlington transistors and are mounted in Jedecl TO-126 plastic package. They are intenedt for use in industrial switching applications.

The complementary NPN types are the BDX42, BDX43 and BDX44 respectively.

ABSOLUTE MAXIMUM RATINGS

Symbol	Ratings	Value	Unit
- V _{CBO}	Collector-Base Voltage	BDX45 BDX46 BDX47	60 80 90
		BDX45	45
		BDX46 BDX47	60 80
- V _{CER}	Collector-Emitter Voltage	BDX45 BDX46 BDX47	5
		BDX45 BDX46 BDX47	
		BDX45 BDX46 BDX47	V

- I _C	Collector Current	- I _C	BDX45 BDX46 BDX47	1	A
		- I _{CM}	BDX45 BDX46 BDX47	2	
- I _B	Base Current		BDX45 BDX46 BDX47	0.1	A
P _T	Power Dissipation @ T _C = 25°		BDX45 BDX46 BDX47	1.25	Watts
T _J	Junction Temperature		BDX45 BDX46 BDX47	150	
T _S	Storage Temperature		BDX45 BDX46 BDX47	-65 to +150	°C

NJ Semi-Conductors reserves the right to change test conditions, parameters limits and package dimensions without notice information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

Quality Semi-Conductors

PNP BDX45 – BDX46 – BDX47

NPN BDX42 – BDX43– BDX44

THERMAL CHARACTERISTICS

Symbol	Ratings	Value	Unit
R_{thJ-a}	Thermal Resistance, Junction to Ambient BDX45 BDX46 BDX47	100	K/W
R_{thJ-mb}	Thermal Resistance, Junction to Mounting base BDX45 BDX46 BDX47	10	

ELECTRICAL CHARACTERISTICS

TC=25°C unless otherwise noted

Symbol	Ratings	Test Condition(s)	Min	Typ	Mx	Unit
$-I_{CES}$	Collector cut-off current	$V_{BE} = 0 ; -V_{CE} = 45V$ BDX45	-	-	10	μA
		$V_{BE} = 0 ; -V_{CE} = 60V$ BDX46	-	-	10	
		$V_{BE} = 0 ; -V_{CE} = 80V$ BDX47	-	-	10	
$-I_{EBO}$	Emitter cut-off current	$I_C = 0 ; V_{EB} = 4V$ BDX45	-	-	10	μA
		BDX46	-	-	10	
		BDX47	-	-	10	

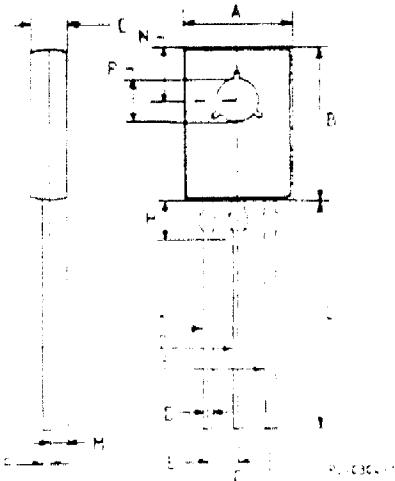
$-V_{CE(SAT)}$	Collector-Emitter saturation Voltage (*)	$-I_C=500 \text{ mA}, -I_B=0.5 \text{ mA}$ BDX45	-	-	1.3	V
		BDX46	-	-	1.3	
		BDX47	-	-	1.3	
		$-I_C=1.0 \text{ A}, -I_B=1.0 \text{ mA}$ BDX46	-	-	1.6	
		BDX45	-	-	1.6	
		BDX47	-	-	1.6	
		$-I_C=1.0 \text{ A}, -I_B=4.0 \text{ mA}$ BDX45	-	-	1.3	
		BDX46	-	-	1.3	
		BDX47	-	-	1.3	
		$-I_C=500 \text{ mA}, -I_B=0.5 \text{ mA}$ BDX46	-	-	1.8	
$-V_{BE(SAT)}$	Base-Emitter saturation Voltage (*)	$T_j=150^\circ C$ BDX45	-	-	1.8	
		BDX46	-	-	1.6	
		BDX47	-	-	1.6	
		$-I_C=1.0 \text{ A}, -I_B=1.0 \text{ mA}$ BDX46	-	-	2.2	
		BDX45	-	-	2.2	
h_{FE}	DC Current Gain	$-I_C=1.0 \text{ A}, -I_B=4.0 \text{ mA}$ BDX47	-	-	2.2	-
		BDX45	1000	-	-	
		$-V_{CE}=10.0 \text{ V}, -I_C=150 \text{ mA}$ BDX46	1000	-	-	
		BDX47	1000	-	-	
		BDX45	2000	-	-	
		BDX46	2000	-	-	
		BDX47	2000	-	-	

PNP BDX45 – BDX46 – BDX47
NPN BDX42 – BDX43– BDX44

Symbol	Ratings	Test Condition(s)	Min	Typ	Mx	Unit
h_{fe}	Small Signal Current Gain	$-V_{CE}=5.0\text{ V}$, $-I_C=500\text{ mA}$, $f=35\text{MHz}$	BDX45 - BDX46 - BDX47 -	10 10 10	-	-
t_{on}	Turn-on time	$-I_C=500\text{ mA}$, $-I_{Bon}=I_{Boff}=0.5\text{ mA}$	BDX45 - BDX46 - BDX47 -	400 400 400	-	ns
t_{off}	Turn-off time		BDX45 - BDX46 - BDX47 -	1500 1500 1500	-	
t_{on}	Turn-on time	$-I_C=1\text{ A}$, $-I_{Bon}=I_{Boff}=1.0\text{ mA}$	BDX45 - BDX46 - BDX47 -	400 400 400	-	
t_{off}	Turn-off time		BDX45 - BDX46 - BDX47 -	1500 1500 1500	-	ns

MECHANICAL DATA CASE TO-126

	DIMENSIONS			
	mm		inches	
	min	max	min	max
A	7.4	7.8	0.295	0.307
B	10.5	10.8	0.413	0.425
C	2.4	2.7	0.094	0.106
D	0.7	0.9	0.027	0.035
E	2.2 typ.		0.087 typ.	
F	0.49	0.75	0.019	0.029
G	4.4 typ.		0.173 typ.	
H	2.54 typ.		0.100 typ.	
L	15.7 typ.		0.618 typ.	
M	1.2 typ.		0.047 typ.	
N	3.8 typ.		0.149 typ.	
P	3.0	3.2	0.118	0.126



Pin 1 :	Emitter
Pin 2 :	Collector
Case :	Base